



ERC30-01--ERC30-02

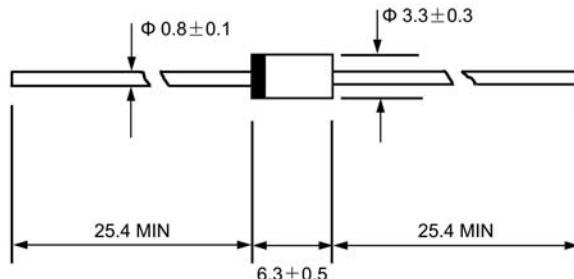
High Efficiency Rectifier

VOLTAGE RANGE: 100 --- 200 V
CURRENT: 1.5 A

DO - 15

Features

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol,Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0



Mechanical Data

- ◇ Case: JEDEC DO-15, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.014 ounces, 0.39 grams
- ◇ Mounting position: Any

Dimensions in millimeters

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		ERC30 - 01	ERC30 - 02	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	100	200	V
Maximum RMS voltage	V_{RMS}	70	140	V
Maximum DC blocking voltage	V_{DC}	100	200	V
Maximum average forward rectified current 9.5mm lead length, $\text{@} T_A = 75^\circ\text{C}$	$I_{F(AV)}$	1.5		A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $\text{@} T_J = 125^\circ\text{C}$	I_{FSM}	60.0		A
Maximum instantaneous forward voltage $\text{@} 1.5\text{A}$	V_F	0.92		V
Maximum reverse current $\text{@} T_A = 25^\circ\text{C}$ at rated DC blocking voltage $\text{@} T_A = 100^\circ\text{C}$	I_R	5.0 100.0		μA
Maximum reverse recovery time (Note1)	t_{rr}	100		ns
Typical junction capacitance (Note2)	C_J	50		pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	50		$^\circ\text{C/W}$
Operating junction temperature range	T_J	- 55 ---- + 150		$^\circ\text{C}$
Storage temperature range	T_{STG}	- 55 ---- + 150		$^\circ\text{C}$

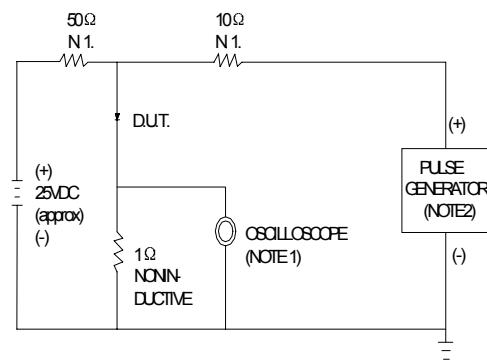
NOTE: 1. Measured with $I_F=0.5\text{A}$, $I_R=1\text{A}$, $I_{rr}=0.25\text{A}$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

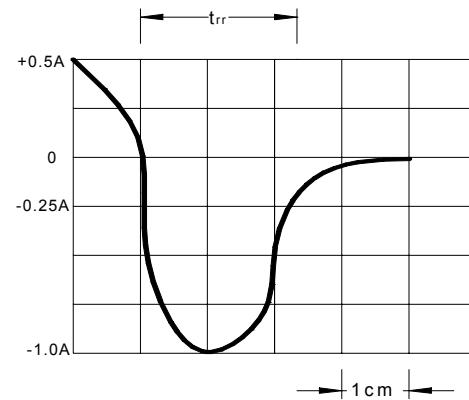
3. Thermal resistance from junction to ambient.

Ratings AND Characteristic Curves

FIG.1 -TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. RISE TIME=7ns MAX. INPUT IMPEDANCE=1MΩ 22pF
2. RISE TIME=10ns MAX. SOURCE IMPEDANCE=50Ω.



SET TIME BASE FOR 20/30 ns/cm

FIG.2 -FORWARD DERATING CURVE

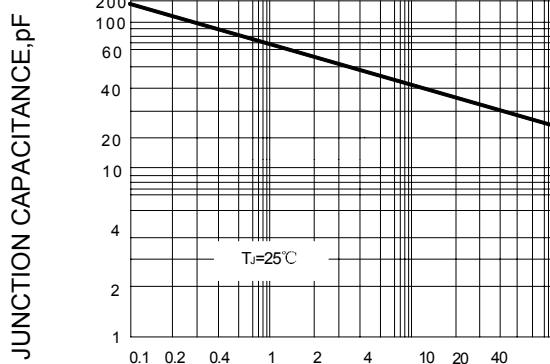
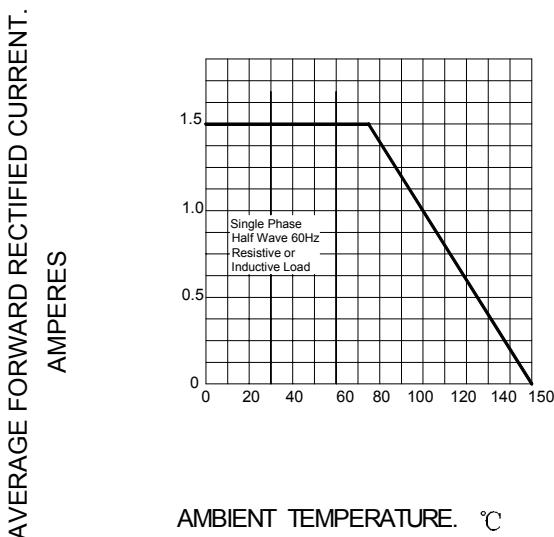


FIG.4-PEAK FORWARD SURGE CURRENT

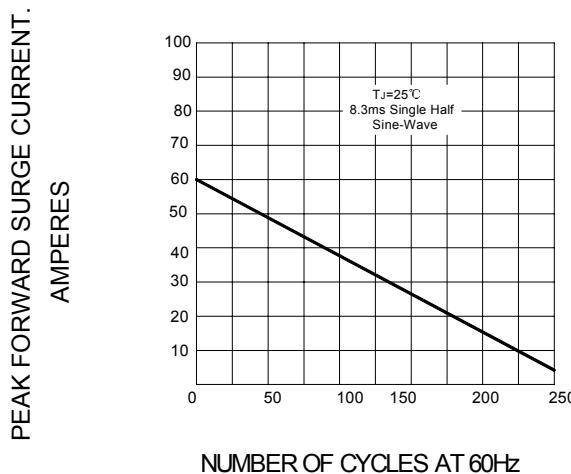


FIG.5 – TYPICAL FORWARD CHARACTERISTIC

